RECTRON
SEMICONDUCTOR
TECHNICAL SPECIFICATION

1F10 THRU 1F18

FAST RECOVERY RECTIFIER

VOLTAGE RANGE 1000 to 1800 Volts CURRENT 0.5 Ampere

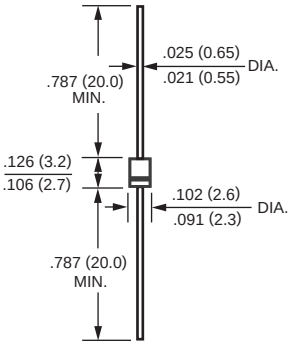
FEATURES

* Fast switching
* Low leakage
* Low forward voltage drop
* High current capability
* High currenf surge
* High reliability

MECHANICAL DATA

* Case: Molded plastic
* Epoxy: Device has UL flammability classification 94V-O
* Lead: MIL-STD-202E method 208C guaranteed
* Mounting position: Any
* Weight: 0.19 gram

R-1



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	1F10	1F12	1F14	1F15	1F16	1F18	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1000	1200	1400	1500	1600	1800	Volts
Maximum RMS Voltage	V_{RMS}	700	840	980	1050	1120	1260	Volts
Maximum DC Blocking Voltage	V_{DC}	1000	1200	1400	1500	1600	1800	Volts
Maximum Average Forward Rectified Current at T_A = 25°C	I_O	0.5						Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	25						Amps
Typical Junction Capacitance (Note 2)	C_J	15						pF
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to + 150						°C

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	1F10	1F12	1F14	1F15	1F16	1F18	UNITS
Maximum Instantaneous Forward Voltage at 0.5A DC	V_F	1.8						Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage T_A = 25°C	I_R	5.0						uAmps
Maximum Full Load Reverse Current Full Cycle Average, .375" (9.5mm) lead length at T_L = 55°C		100						uAmps
Maximum Reverse Recovery Time (Note 1)	trr	300						nSec

NOTES : 1. Reverse Recovery Test Conditions: I_F = 0.5A, I_R = -1.0A, I_{RR} =- 0.25A
2. Measured at 1 MHz and applied reverse voltage of 4.0 volts

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RATING AND CHARACTERISTIC CURVES (1F10 THRU 1F18)

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

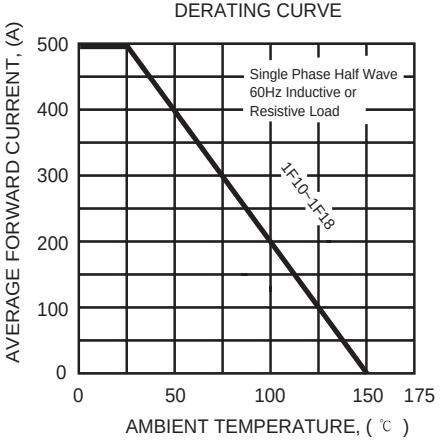


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

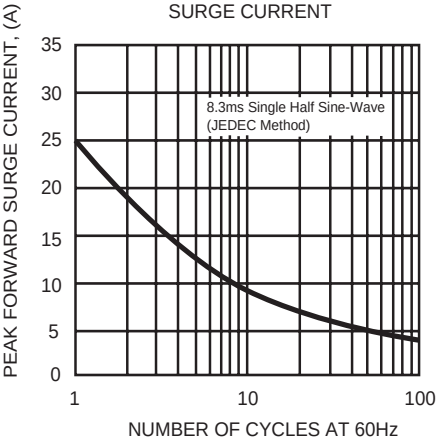
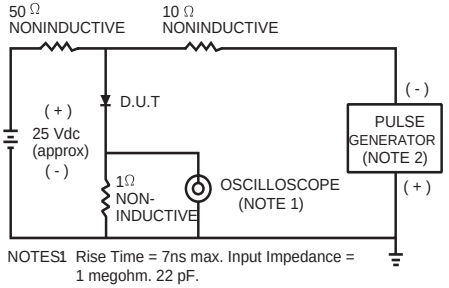


FIG. 3 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES 1. Rise Time = 7ns max. Input Impedance = 1 megohm. 22 pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.